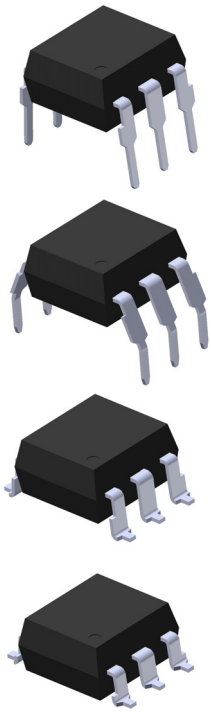
6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

4N2X Series
4N3X Series
H11AX Series

Features:

- 4N2X series: 4N25, 4N26, 4N27, 4N28
- 4N3X series: 4N35, 4N36, 4N37, 4N38
- H11AX series: H11A1, H11A2, H11A3, H11A4, H11A5
- High isolation voltage between input and output (Viso=5000 V rms)
- Creepage distance >7.62 mm
- Operating temperature up to +110°C
- Compact dual-in-line package
- Pb free and RoHS compliant.
- UL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approval
- DEMKO approval
- FIMKO approval
- CSA approved
- CQC approved



Description

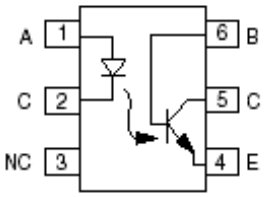
The 4N2X, 4N3X, H11AX series of devices each consist of an infrared emitting diode optically coupled to a phototransistor.

They are packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

Applications

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs

Schematic



1. Anode
2. Cathode
3. No Connection
4. Emitter
5. Collector
6. Base

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

Absolute Maximum Ratings (T_a=25°C)

Parameter		Symbol	Rating	Unit
Input	Forward current	I_F	60	mA
	Peak forward current (t = 10μs)	I_{FM}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation (T_A = 25°C)	P_D	100	mW
	Derating factor (above 100°C)		3.8	mW/°C
Output	Collector-Emitter voltage	V_{CEO}	80	V
	Collector-Base voltage	V_{CBO}	80	V
	Emitter-Collector voltage	V_{ECO}	7	V
	Emitter-Base voltage	V_{EBO}	7	V
	Power dissipation (T_A = 25°C)	P_C	150	mW
	Derating factor (above 100°C)		9.0	mW/°C
Total power dissipation		P_{tot}	200	mW
Isolation voltage *1		V_{iso}	5000	Vrms
Operating temperature		T_{opr}	-55~+110	°C
Storage temperature		T_{stg}	-55~+125	°C
Soldering temperature *2		T_{sol}	260	°C

Notes

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together.

*2 For 10 seconds.

Electrical Characteristics (T_a=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.*	Max.	Unit	Condition
Forward voltage	V_F	-	1.2	1.5	V	I_F = 10mA
Reverse current	I_R	-	-	10	μA	V_R = 6V
Input capacitance	C_{in}	-	30	-	pF	V = 0, f = 1MHz

Output

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Condition
Collector-Base dark current		I_{CBO}	-	-	20	nA	V_{CB} = 10V
Collector-Emitter dark current	4N2X H11AX	I_{CEO}	-	-	50	nA	V_{CE} = 10V, IF=0mA
	4N3X		-	-	50		V_{CE} = 60V, IF=0mA
Collector-Emitter breakdown voltage		BV_{CEO}	80	-	-	V	I_c=1mA
Collector-Base breakdown voltage		BV_{CBO}	80	-	-	V	I_C=0.1mA
Emitter-Collector breakdown voltage		BV_{ECO}	7	-	-	V	I_E=0.1mA
Emitter-Base breakdown voltage		BV_{EBO}	7	-	-	V	I_E=0.1mA
Collector-Emitter capacitance		C_{CE}	-	8	-	pF	VCE=0V, f=1MHz

* Typical values at T_a = 25°C

Transfer Characteristics (T_a=25°C unless specified otherwise)

Parameter		Symbol	Min.	Typ.*	Max.	Unit	Condition
Current transfer ratio	4N35, 4N36, 4N37	CTR	100	-	-	%	I_F = 10mA, V_{CE} = 10V
	H11A1		50	-	-		
	H11A5		30	-	-		
	4N25, 4N26, 4N38, H11A2, H11A3		20	-	-		
	4N27, 4N28, H11A4		10	-	-		
Collector-Emitter saturation voltage	4N25, 4N26, 4N27, 4N28	$V_{CE(sat)}$	-	-	0.5	V	I_F = 50mA, I_c = 2mA
	4N35, 4N36, 4N37		-	-	0.3		I_F = 10mA, I_c = 0.5mA
	H11A1, H11A2, H11A3, H11A4, H11A5		-	-	0.4		
	4N38		-	-	1.0		I_F = 20mA, I_c = 4mA
Isolation resistance		R_{IO}	10^{11}	-	-	Ω	V_{IO} = 500Vdc
Input-output capacitance		C_{IO}	-	0.2	-	pF	V_{IO} = 0, f = 1MHz
Turn-on time	4N25, 4N26, 4N27, 4N28, H11A1, H11A2, H11A3, H11A4, H11A5	Ton	-	3	10	μs	V_{CC} = 10V, I_F = 10mA, R_L = 100Ω See Fig. 11
	4N35, 4N36, 4N37, 4N38		-	10	12		V_{CC} = 10V, I_C = 2mA, R_L = 100Ω, See Fig. 11
Turn-off time	4N25, 4N26, 4N27, 4N28, H11A1, H11A2, H11A3, H11A4	Toff	-	3	10	μs	V_{CC} = 10V, I_F = 10mA, R_L = 100Ω See Fig. 11
	4N35, 4N36, 4N37, 4N38		-	9	12		V_{CC} = 10V, I_C = 2mA, R_L = 100Ω, See Fig. 11

* Typical values at T_a = 25°C

Typical Performance Curves

Figure 1. Forward Current vs Forward Voltage

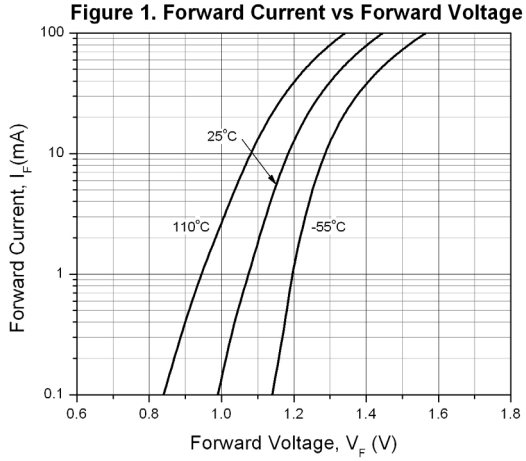


Figure 2. Current Tranfer Ratio vs Forward Current

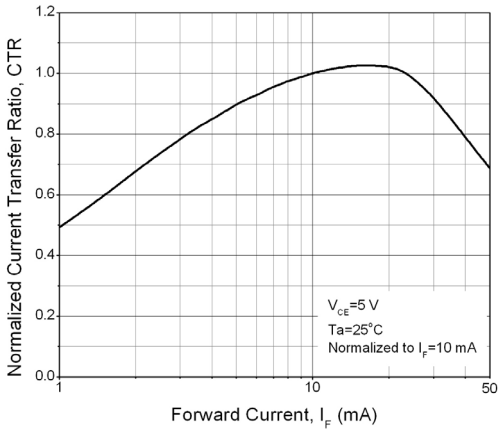


Figure 3. Current Tranfer Ratio vs Ambient Temperature

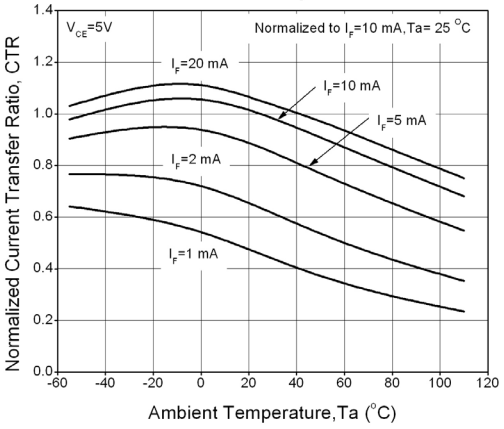


Figure 4. Current Transfer Ratio (Saturated) vs Base-Emitter Resistance

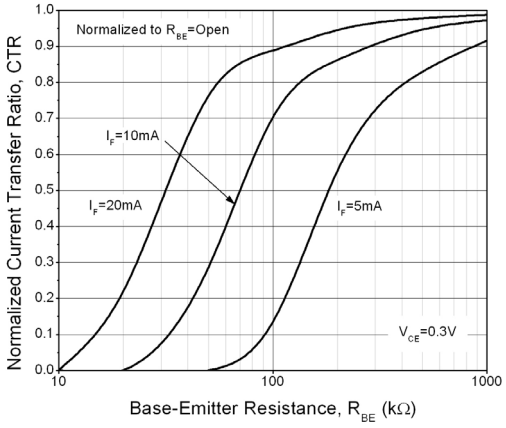


Figure 5. Current Transfer Ratio (Unsaturated) vs Base-Emitter Resistance

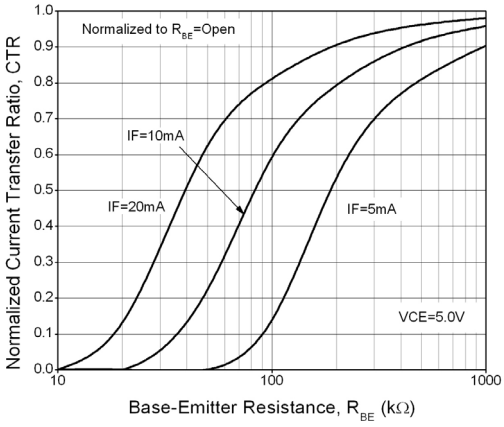


Figure 6. Dark Current vs Ambient Temperature

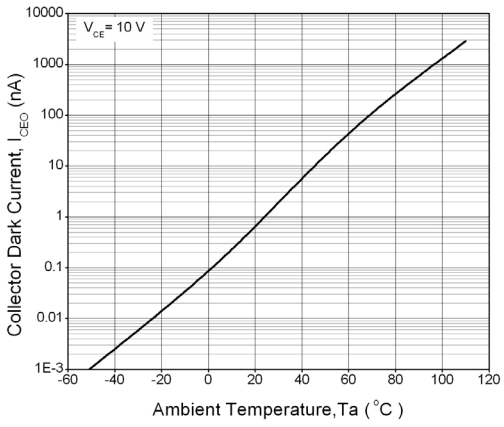


Figure 7. Collector-Emitter Saturation Voltage vs Collector Current

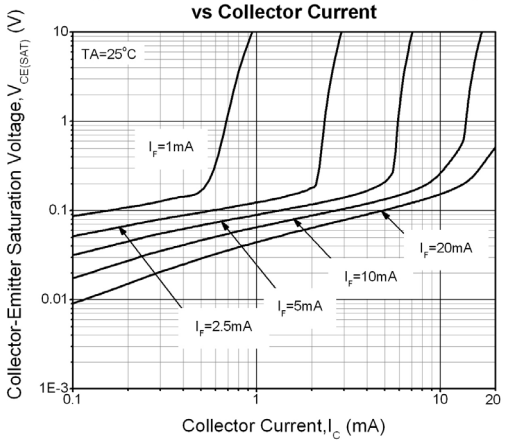


Figure 8. Switching Time vs Load Resistance

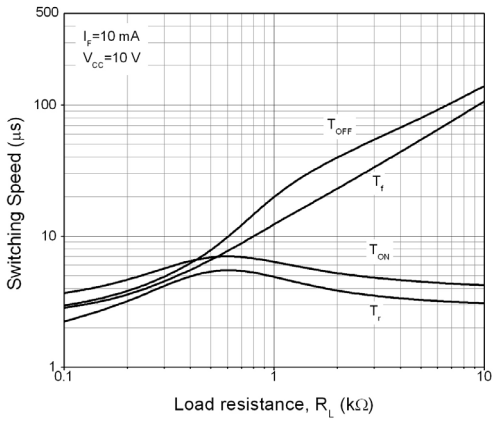


Figure 9. Turn-on Time vs Base-Emitter Resistance)

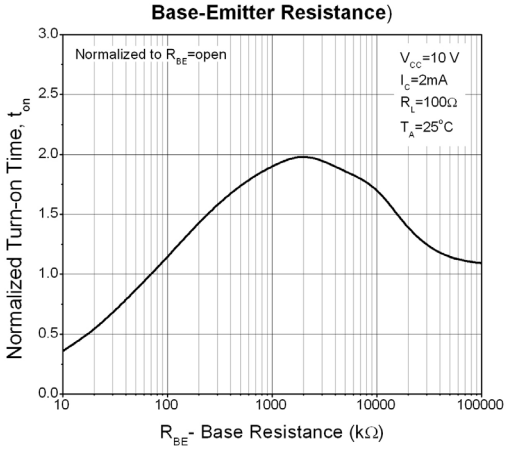
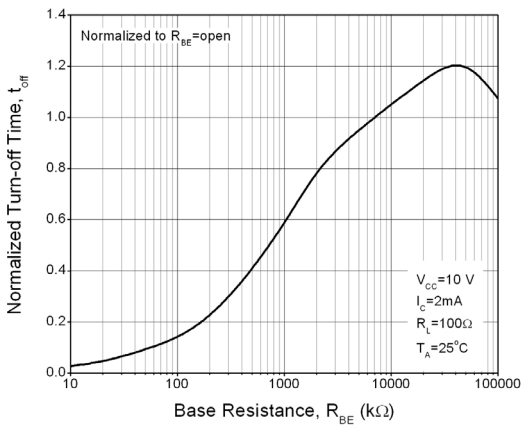


Figure 10. Turn-off Time vs Base-Emitter Resistance



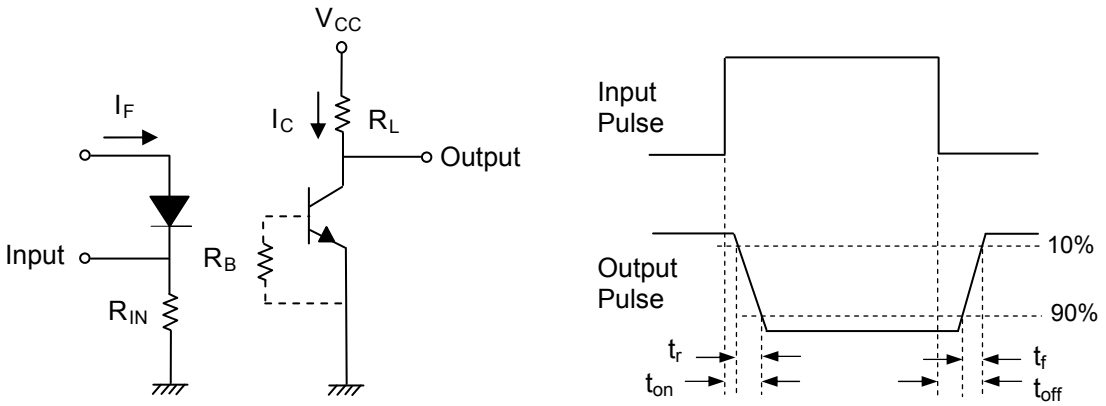


Figure 11. Switching Time Test Circuit & Waveforms

Order Information

Part Number

4NXXY(Z)-V

or

H11AXY(Z)-V

Note

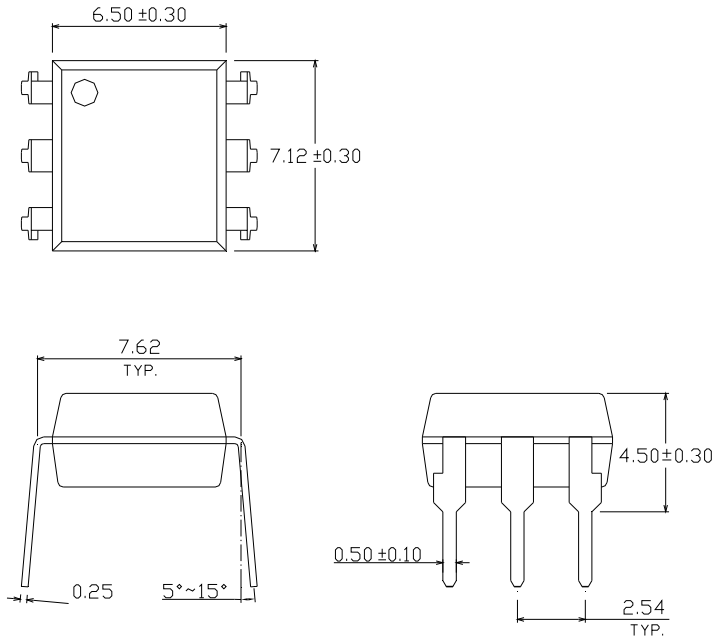
XX = Part no. for 4NXX series (25, 26, 27, 28, 35, 36, 37 or 38)
X = Part no. for H11AX series (1, 2, 3, 4, or 5)
Y = Lead form option (S, S1, M or none)
Z = Tape and reel option (TA, TB or none).
V = VDE safety (optional)

Option	Description	Packing quantity
None	Standard DIP-6	65 units per tube
M	Wide lead bend (0.4 inch spacing)	65 units per tube
S (TA)	Surface mount lead form + TA tape & reel option	1000 units per reel
S (TB)	Surface mount lead form + TB tape & reel option	1000 units per reel
S1 (TA)	Surface mount lead form (low profile) + TA tape & reel option	1000 units per reel
S1 (TB)	Surface mount lead form (low profile) + TB tape & reel option	1000 units per reel

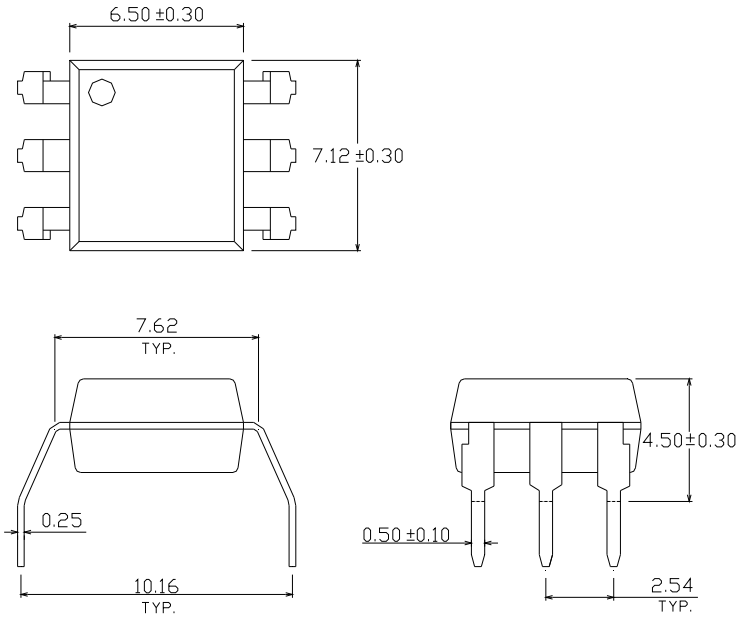
Package Drawings

(Dimensions in mm)

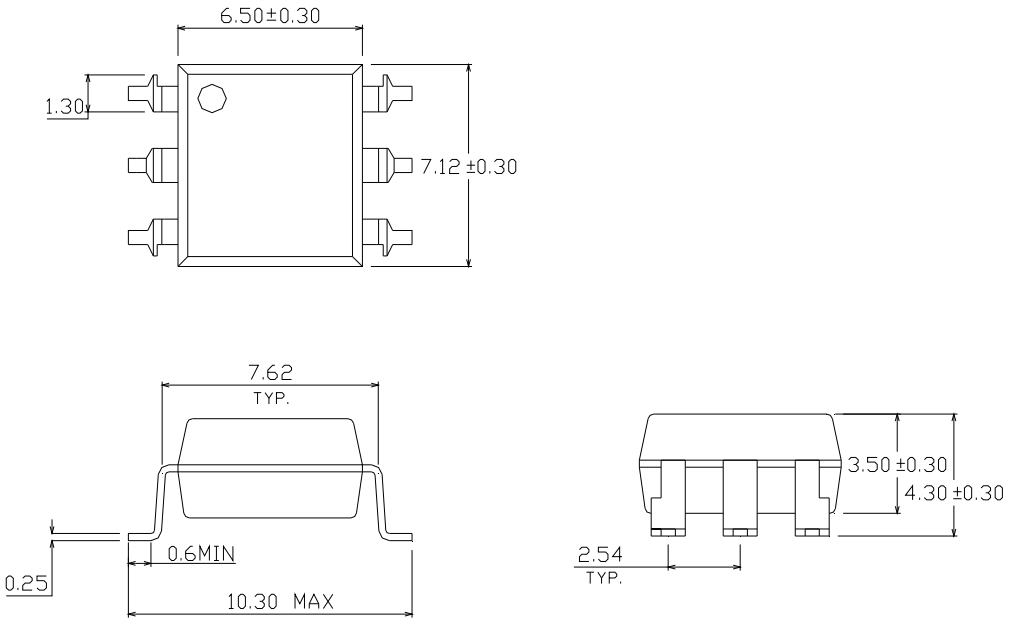
Standard DIP Type



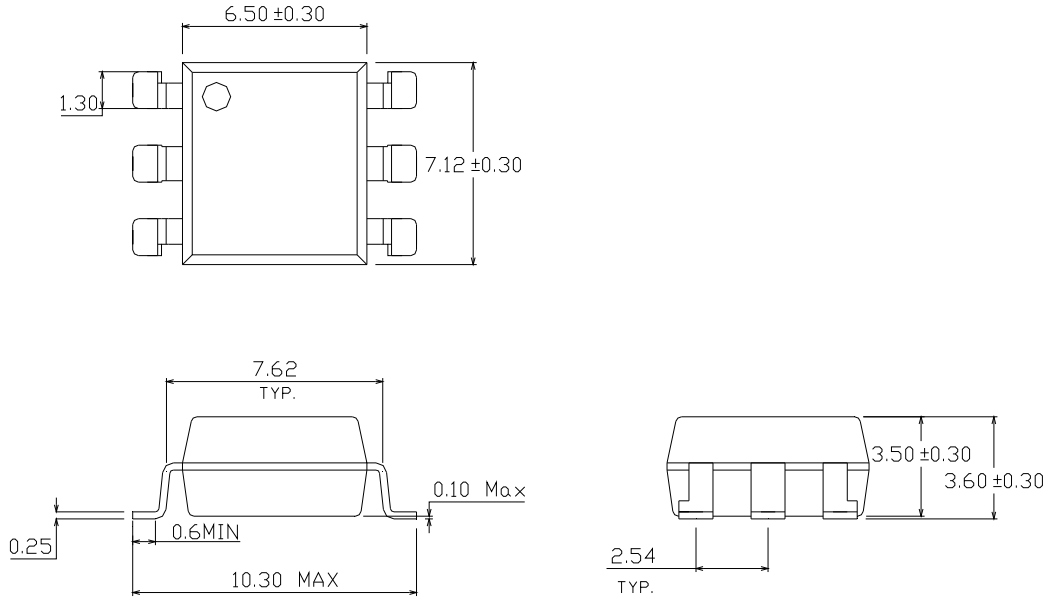
Option M Type



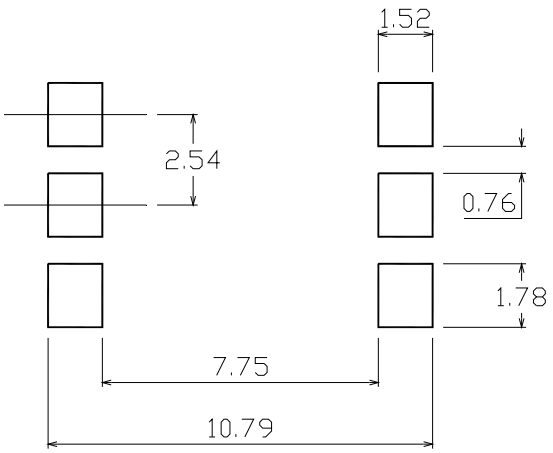
Option S Type



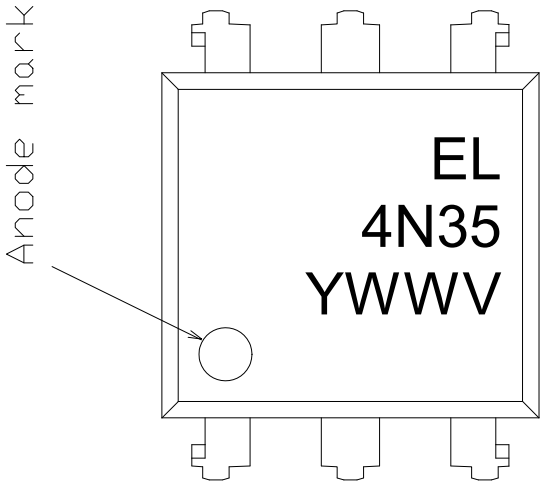
Option S1 Type



Recommended pad layout for surface mount leadform



Device Marking



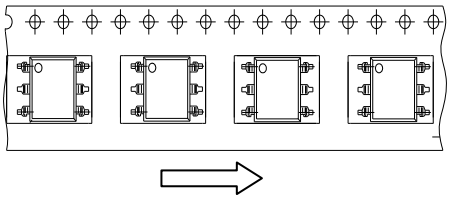
Notes

EL	denotes Everlight
4N35	denotes Device Number
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

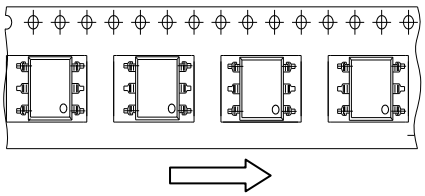
Tape & Reel Packing Specifications

Option TA



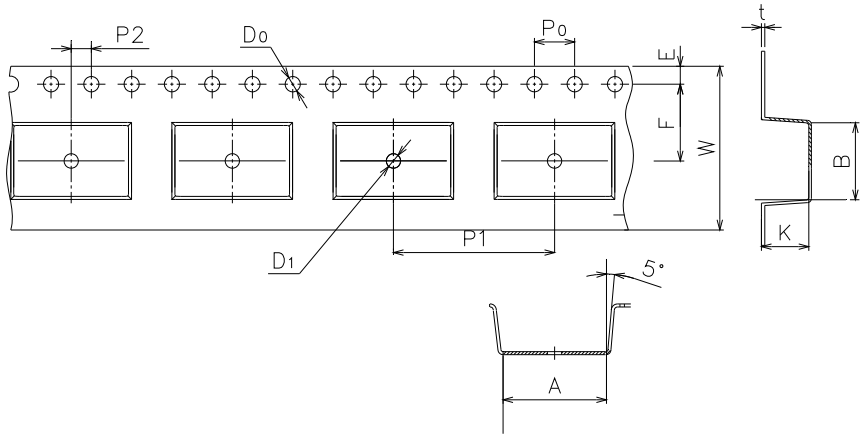
Direction of feed from reel

Option TB



Direction of feed from reel

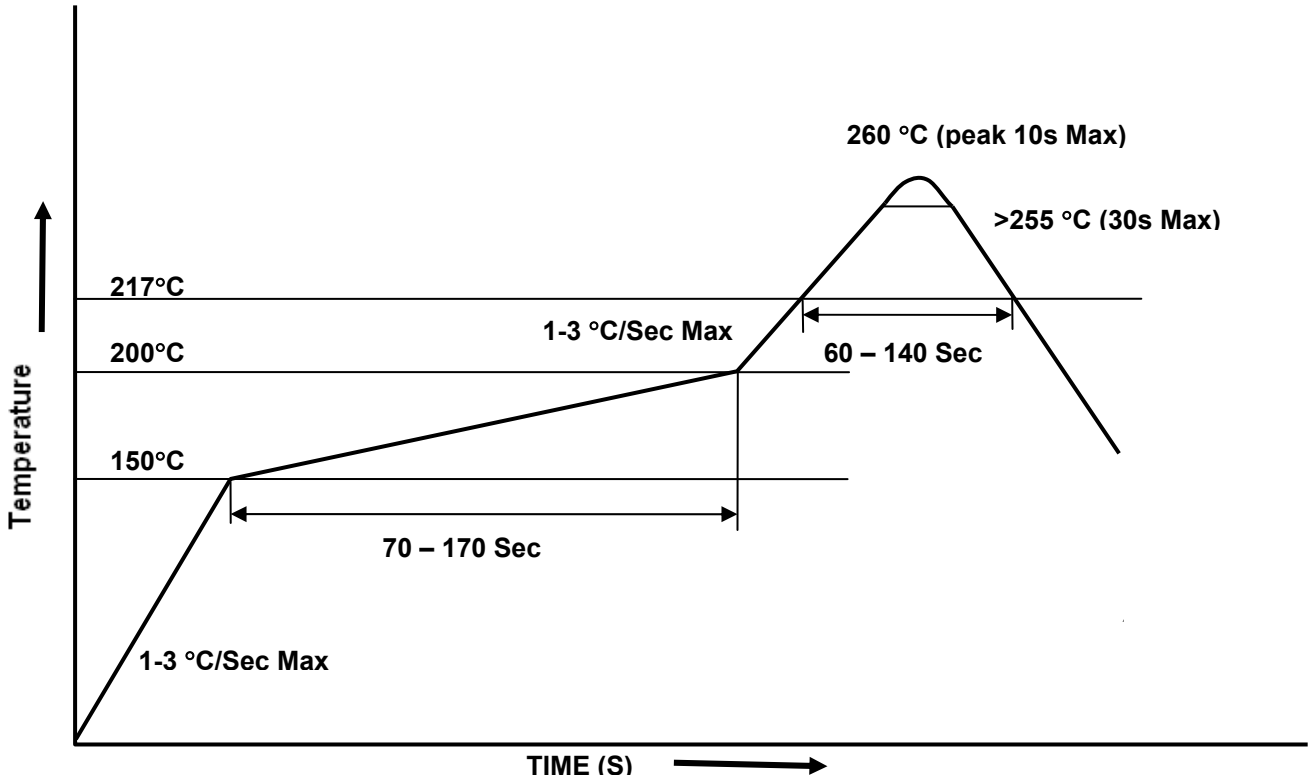
Tape dimensions



Dimension No.	A	B	Do	D1	E	F
Dimension (mm)	10.4±0.1	7.52±0.1	1.5±0.1	1.5+0.1/-0	1.75±0.1	7.5±0.1

Dimension No.	Po	P1	P2	t	W	K
Dimension (mm)	4.0±0.15	16.0±0.1	2.0±0.1	0.35±0.03	16.0±0.2	4.5±0.1

Solder Reflow Temperature Profile



DISCLAIMER

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2. When using this product, please observe the absolute maximum ratings and the instructions for use as outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.

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- *Специальные условия для постоянных клиентов.*
- *Подбор аналогов.*
- *Поставку компонентов в любых объемах, удовлетворяющих вашим потребностям.*

- *Приемлемые сроки поставки, возможна ускоренная поставка.*
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- *Сертификаты соответствия на поставляемую продукцию (по желанию клиента).*
- *Тестирование поставляемой продукции.*
- *Поставку компонентов, требующих военную и космическую приемку.*
- *Входной контроль качества.*
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- *Техническую поддержку проекта.*
- *Защиту от снятия компонента с производства.*
- *Оценку стоимости проекта по компонентам.*
- *Изготовление тестовой платы монтаж и пусконаладочные работы.*

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